

PESDxS1UB series

ESD protection diodes in SOD523 package

Rev. 02 — 24 August 2009

Product data sheet

1. Product profile

1.1 General description

Unidirectional ESD protection diode in a SOD523 plastic package designed to protect one transmission or data line from the damage caused by ESD (ElectroStatic Discharge) and other transients.

1.2 Features

- Unidirectional ESD protection of one line
- Max. peak pulse power: $P_{PP} = 330 \text{ W}$ at $t_p = 8/20 \mu\text{s}$
- Low clamping voltage: $V_{CL} = 20 \text{ V}$ at $I_{PP} = 18 \text{ A}$
- Ultra low leakage current: $I_{RM} < 700 \text{ nA}$
- ESD protection $> 23 \text{ kV}$
- IEC 61000-4-2, level 4 (ESD)
- IEC 61000-4-5 (surge); $I_{PP} = 18 \text{ A}$ at $t_p = 8/20 \mu\text{s}$

1.3 Applications

- Computers and peripherals
- Communication systems
- Audio and video equipment
- Data lines
- CAN bus protection

1.4 Quick reference data

Table 1. Quick reference data


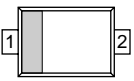
Symbol	Parameter	Conditions	Value	Unit
V_{RWM}	reverse standoff voltage			
	PESD3V3S1UB		3.3	V
	PESD5V0S1UB		5	V
	PESD12VS1UB		12	V
	PESD15VS1UB		15	V
	PESD24VS1UB		24	V

Table 1. Quick reference data ...continued

Symbol	Parameter	Conditions	Value	Unit
C _d	diode capacitance	V _R = 0 V; f = 1 MHz		
	PESD3V3S1UB		207	pF
	PESD5V0S1UB		152	pF
	PESD12VS1UB		38	pF
	PESD15VS1UB		32	pF
	PESD24VS1UB		23	pF
	number of protected lines		1	

2. Pinning information

Table 2. Discrete pinning

Pin	Description	Simplified outline	Symbol
1	cathode	[1]	 sym035
2	anode		

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
PESDxS1UB	SC -79	plastic surface mounted package; 2 leads	SOD523

4. Marking

Table 4. Marking

Type number	Marking code
PESD3V3S1UB	N1
PESD5V0S1UB	N2
PESD12VS1UB	N3
PESD15VS1UB	N4
PESD24VS1UB	N5

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{PP}	peak pulse power	8/20 μs	[1]		
	PESD3V3S1UB		-	330	W
	PESD5V0S1UB		-	260	W
	PESD12VS1UB		-	180	W
	PESD15VS1UB		-	160	W
	PESD24VS1UB		-	160	W
I _{PP}	peak pulse current	8/20 μs	[1]		
	PESD3V3S1UB		-	18	A
	PESD5V0S1UB		-	15	A
	PESD12VS1UB		-	5	A
	PESD15VS1UB		-	5	A
	PESD24VS1UB		-	3	A
T _j	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Non-repetitive current pulse 8/20 μs exponentially decay waveform; see [Figure 1](#).

Table 6. ESD maximum ratings

Symbol	Parameter	Conditions	Min	Max	Unit
ESD	electrostatic discharge capability	IEC 61000-4-2 (contact discharge)	[1]		
	PESD3V3S1UB		-	30	kV
	PESD5V0S1UB		-	30	kV
	PESD12VS1UB		-	30	kV
	PESD15VS1UB		-	30	kV
	PESD24VS1UB		-	23	kV
	PESDxS1UB series	HBM MIL-STD883	-	10	kV

[1] Device stressed with ten non-repetitive ElectroStatic Discharge (ESD) pulses; see [Figure 2](#).

Table 7. ESD standards compliance

Standard	Conditions
IEC 61000-4-2, level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
HBM MIL-STD883, class 3	> 4 kV

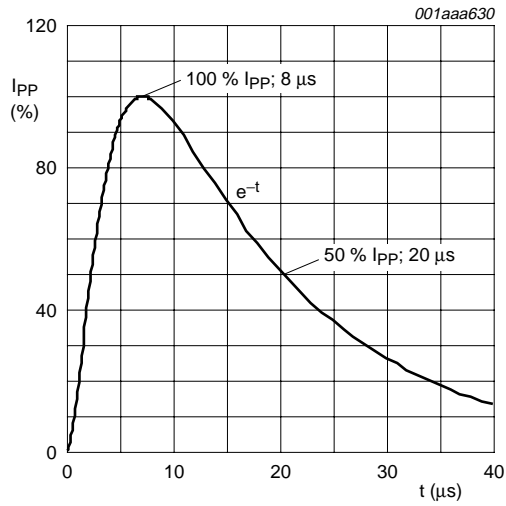


Fig 1. 8/20 μs pulse waveform according to IEC 61000-4-5

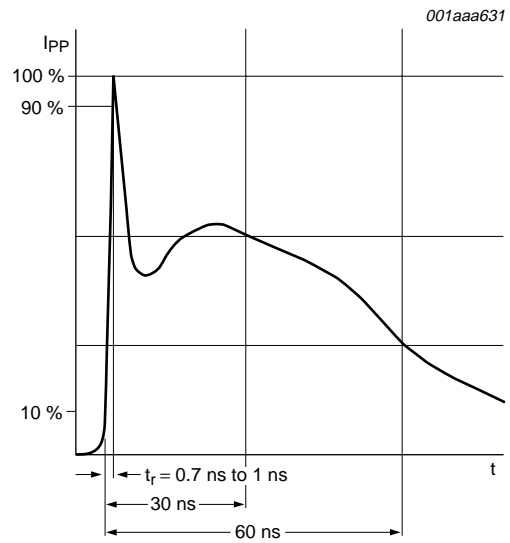


Fig 2. ElectroStatic Discharge (ESD) pulse waveform according to IEC 61000-4-2

6. Characteristics

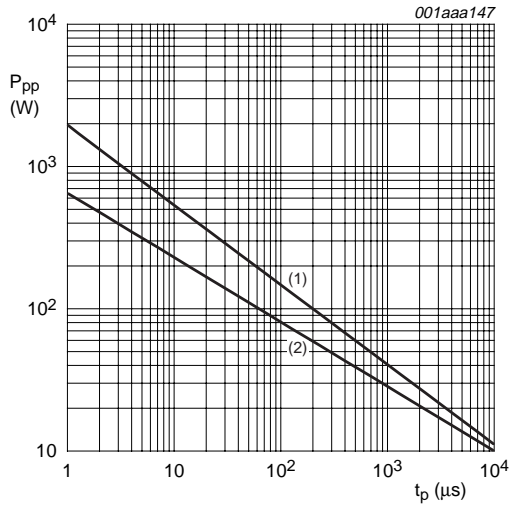
Table 8. Characteristics
 $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RWM}	reverse standoff voltage					
	PESD3V3S1UB		-	-	3.3	V
	PESD5V0S1UB		-	-	5	V
	PESD12VS1UB		-	-	12	V
	PESD15VS1UB		-	-	15	V
	PESD24VS1UB		-	-	24	V
I_{RM}	reverse leakage current	see Figure 7				
	PESD3V3S1UB	$V_{RWM} = 3.3\text{ V}$	-	0.7	2	μA
	PESD5V0S1UB	$V_{RWM} = 5\text{ V}$	-	0.1	1	μA
	PESD12VS1UB	$V_{RWM} = 12\text{ V}$	-	< 1	50	nA
	PESD15VS1UB	$V_{RWM} = 15\text{ V}$	-	< 1	50	nA
	PESD24VS1UB	$V_{RWM} = 24\text{ V}$	-	< 1	50	nA
V_{BR}	breakdown voltage	$I_R = 5\text{ mA}$				
	PESD3V3S1UB		5.2	5.6	6.0	V
	PESD5V0S1UB		6.4	6.8	7.2	V
	PESD12VS1UB		14.7	15.0	15.3	V
	PESD15VS1UB		17.6	18.0	18.4	V
	PESD24VS1UB		26.5	27.0	27.5	V
C_d	diode capacitance	$V_R = 0\text{ V}$; $f = 1\text{ MHz}$; see Figure 5 and 6				
	PESD3V3S1UB		-	207	300	pF
	PESD5V0S1UB		-	152	200	pF
	PESD12VS1UB		-	38	75	pF
	PESD15VS1UB		-	32	70	pF
	PESD24VS1UB		-	23	50	pF
$V_{(CLR)}$	clamping voltage			[1]		
	PESD3V3S1UB	$I_{PP} = 1\text{ A}$	-	-	7	V
		$I_{PP} = 18\text{ A}$	-	-	20	V
	PESD5V0S1UB	$I_{PP} = 1\text{ A}$	-	-	9	V
		$I_{PP} = 15\text{ A}$	-	-	20	V
	PESD12VS1UB	$I_{PP} = 1\text{ A}$	-	-	19	V
		$I_{PP} = 5\text{ A}$	-	-	35	V
	PESD15VS1UB	$I_{PP} = 1\text{ A}$	-	-	23	V
		$I_{PP} = 5\text{ A}$	-	-	40	V
	PESD24VS1UB	$I_{PP} = 1\text{ A}$	-	-	36	V
		$I_{PP} = 3\text{ A}$	-	-	70	V

Table 8. Characteristics ...continued $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
R_{diff}	differential resistance					
	PESD3V3S1UB	$I_R = 1\text{ mA}$	-	-	400	Ω
	PESD5V0S1UB	$I_R = 1\text{ mA}$	-	-	80	Ω
	PESD12VS1UB	$I_R = 1\text{ mA}$	-	-	200	Ω
	PESD15VS1UB	$I_R = 1\text{ mA}$	-	-	225	Ω
	PESD24VS1UB	$I_R = 0.5\text{ mA}$	-	-	300	Ω

[1] Non-repetitive current pulse 8/20 μs exponentially decay waveform; see [Figure 1](#).



T_{amb} = 25 °C

t_p = 8/20 μs exponentially decay waveform, see [Figure 1](#)

- (1) PESD3V3S1UB and PESD5V0S1UB
- (2) PESD12VS1UB, PESD15VS1UB; PESD24VS1UB

Fig 3. Peak pulse power dissipation as a function of pulse time; typical values

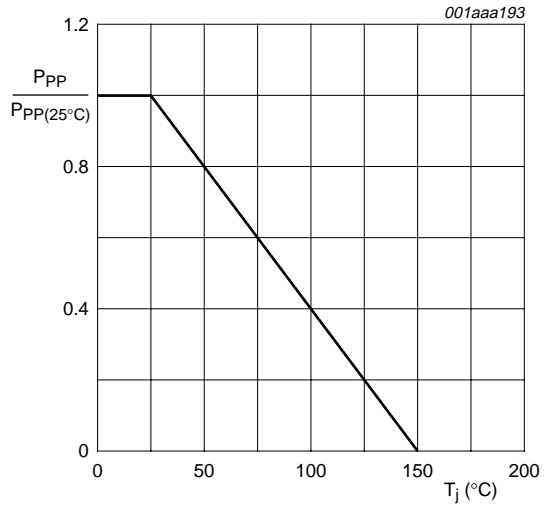
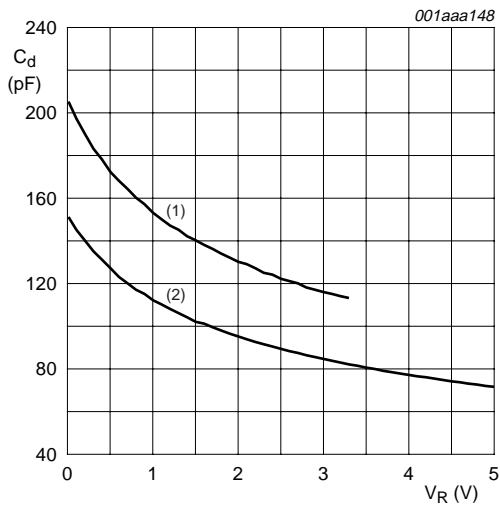


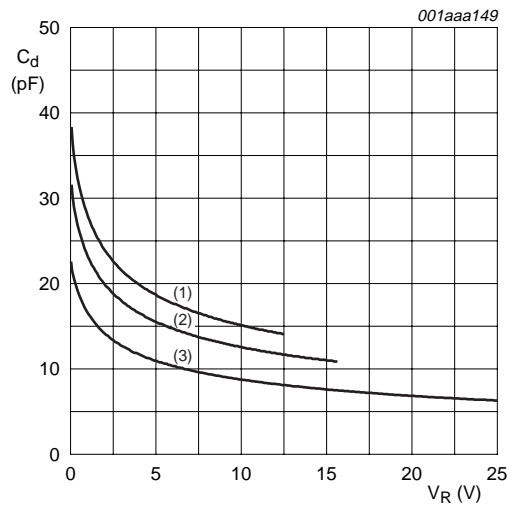
Fig 4. Relative variation of peak pulse power as a function of junction temperature; typical values



f = 1 MHz; T_{amb} = 25 °C

- (1) PESD3V3S1UB
- (2) PESD5V0S1UB

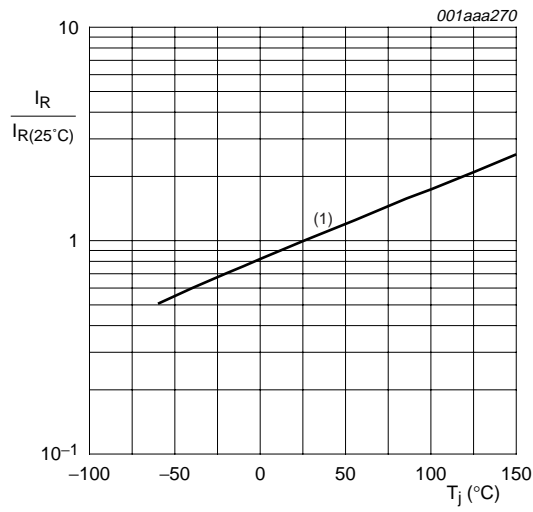
Fig 5. Diode capacitance as a function of reverse voltage; typical values



f = 1 MHz; T_{amb} = 25 °C

- (1) PESD12VS1UB
- (2) PESD15VS1UB
- (3) PESD24VS1UB

Fig 6. Diode capacitance as a function of reverse voltage; typical values



- (1) PESD3V3S1UB; $V_{RWM} = 3.3$ V
- PESD5V0S1UB; $V_{RWM} = 5$ V
- I_R is less than 10 nA at 150 °C for:
- PESD12VS1UB; $V_{RWM} = 12$ V
- PESD15VS1UB; $V_{RWM} = 15$ V
- PESD24VS1UB; $V_{RWM} = 24$ V

Fig 7. Relative variation of reverse leakage current as a function of junction temperature; typical values

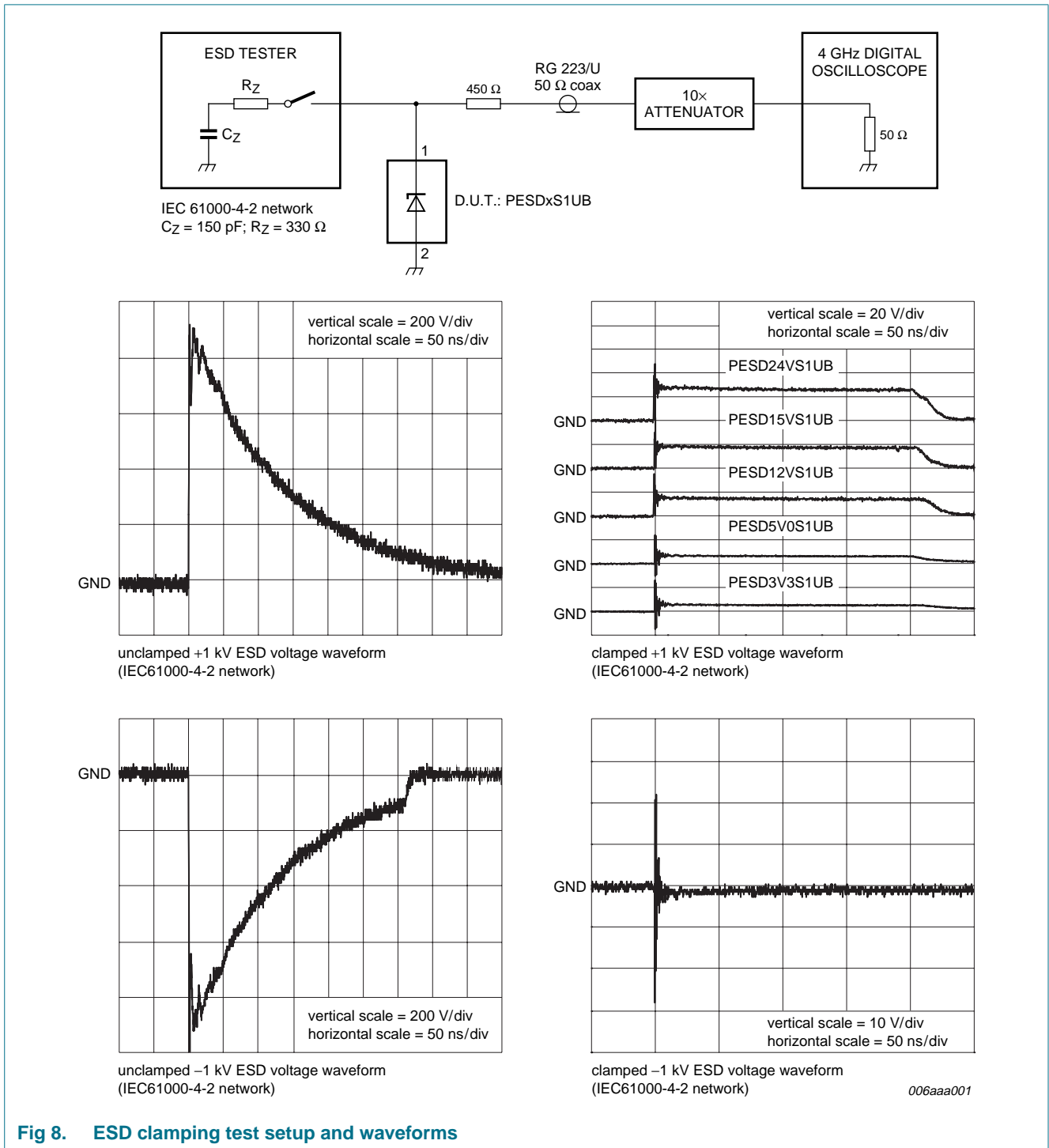


Fig 8. ESD clamping test setup and waveforms

7. Application information

The PESDxS1UB series is designed for unidirectional protection of one single data line from the damage caused by ESD (ElectroStatic Discharge) and Surge Pulses. The PESDxS1UB series may be used on lines where the signal polarity is above or below ground. The PESDxS1UB series provides a surge capability of up to 330 Watts per line for a 8/20 μ s waveform.

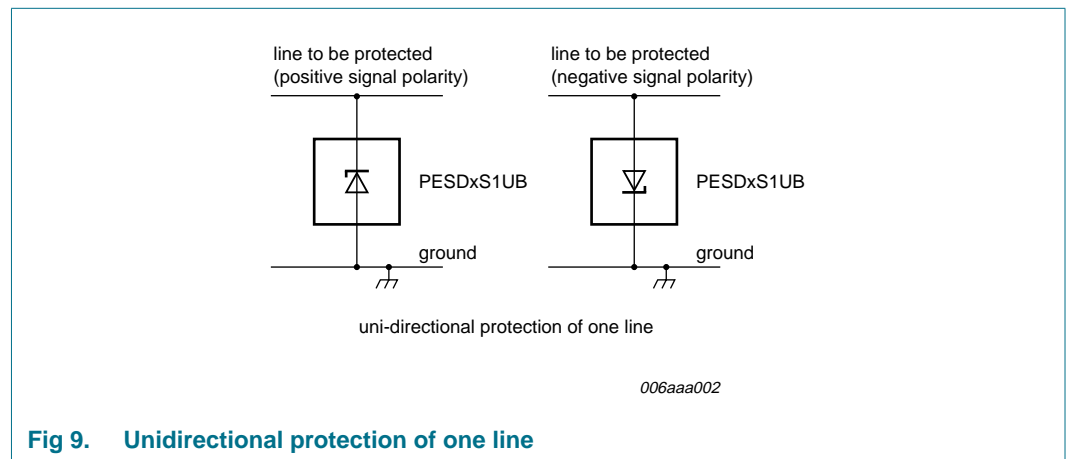


Fig 9. Unidirectional protection of one line

Circuit board layout and protection device placement:

Circuit board layout is critical for the suppression of ESD, EFT and Surge transients. The following guidelines are recommended:

1. Place the protection device as close to the input terminal or connector as possible.
2. The path length between the protection device and the protected line should be minimized.
3. Keep parallel signal paths to a minimum.
4. Avoid running protection conductors in parallel with unprotected conductor.
5. Minimize all printed-circuit board conductive loops including power and ground loops.
6. Minimize the length of the transient return path to ground.
7. Avoid using shared transient return paths to a common ground point.
8. Ground planes should be used whenever possible. For multilayer printed-circuit boards, use ground vias.

8. Package outline

Plastic surface-mounted package; 2 leads

SOD523

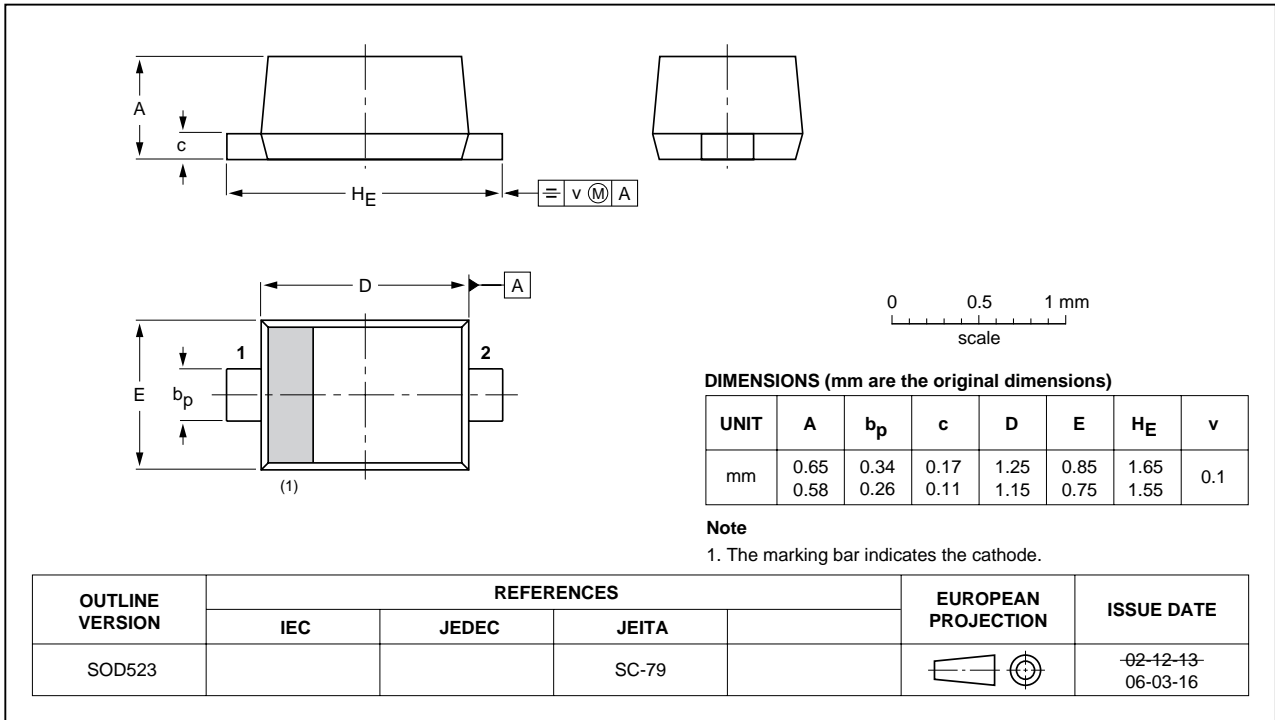


Fig 10. Package outline

9. Packing information

Table 9. Possible packing methods

The indicated -xxx are the last three digits of the 12 NC ordering code.^[1]

Type number	Package	Description	Packing quantity	
			3000	10000
PESD3V3S1UB	SOD523	4 mm pitch, 8 mm tape and reel	-115	-135
PESD5V0S1UB	SOD523	4 mm pitch, 8 mm tape and reel	-115	-135
PESD12VS1UB	SOD523	4 mm pitch, 8 mm tape and reel	-115	-135
PESD15VS1UB	SOD523	4 mm pitch, 8 mm tape and reel	-115	-135
PESD24VS1UB	SOD523	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information see [Section 12](#).

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESDXS1UB_SERIES_2	20090824	Product data	-	PESDXS1UB_SERIES_1
Modifications:		<ul style="list-style-type: none">This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content.Figure 10 "Package outline": updated		
PESDXS1UB_SERIES_1	20040614	Product data	-	-

11. Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 24 August 2009

Document identifier: PESDxS1UB_SERIES_2

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